TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

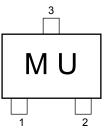
MT3S20TU

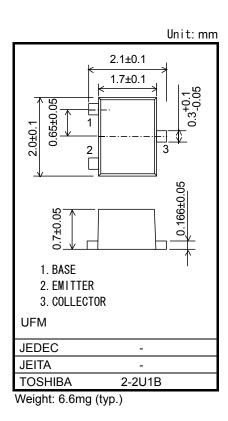
VHF-UHF Band Low-Noise, Low-Distortion Amplifier Applications

FEATURES

- Low Noise Figure:NF=1.45dB(Typ.) (@ f=1GHz)
- High Gain:|S21e|²=12dB(Typ.) (@ f=1GHz)

Marking





Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	20	V
Collector-emitter voltage	V _{CEO}	12	V
Emitter-base voltage	V _{EBO}	1.5	V
Collector current	Ι _C	80	mA
Base current	Ι _Β	10	mA
Collector power dissipation	P _C (Note1)	900	mW
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	–55 to 150	°C

Note.1 : The device is mounted on a ceramic board (25.4 mm x 25.4 mm x 0.8 mm (t))

Note.2 : Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Microwave Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур	Max	Unit
Transition frequency	f _T	V _{CE} =5V,I _C =30mA	5	7		GHz
Insertion gain	S21e ² (1)	V _{CE} =5V,I _C =50mA,f=500MHz	_	17.5		dB
	S21e ² (2)	V _{CE} =5V,I _C =50mA,f=1GHz	10	12		
Noise figure	NF	V _{CE} =5V,I _C =20mA,f=1GHz	_	1.45	2	dB
3 rd order intermodulation distortion output intercept point	OIP3	V _{CE} =5V,I _C =50mA,f=500MHz, ⊿f=1MHz	26	30	_	dBmW

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} =10V,I _E =0	_	_	0.1	μA
Emitter cut-off current	I _{EBO}	V _{EB} =1V,I _C =0	_	_	0.5	μA
DC current gain	h _{FE}	V _{CE} =5V,I _C =50mA	100	150	200	—
Reverse transfer capacitance	C _{re}	V _{CB} =5V,I _E =0, f=1MHz (Note3)		0.75	1	pF

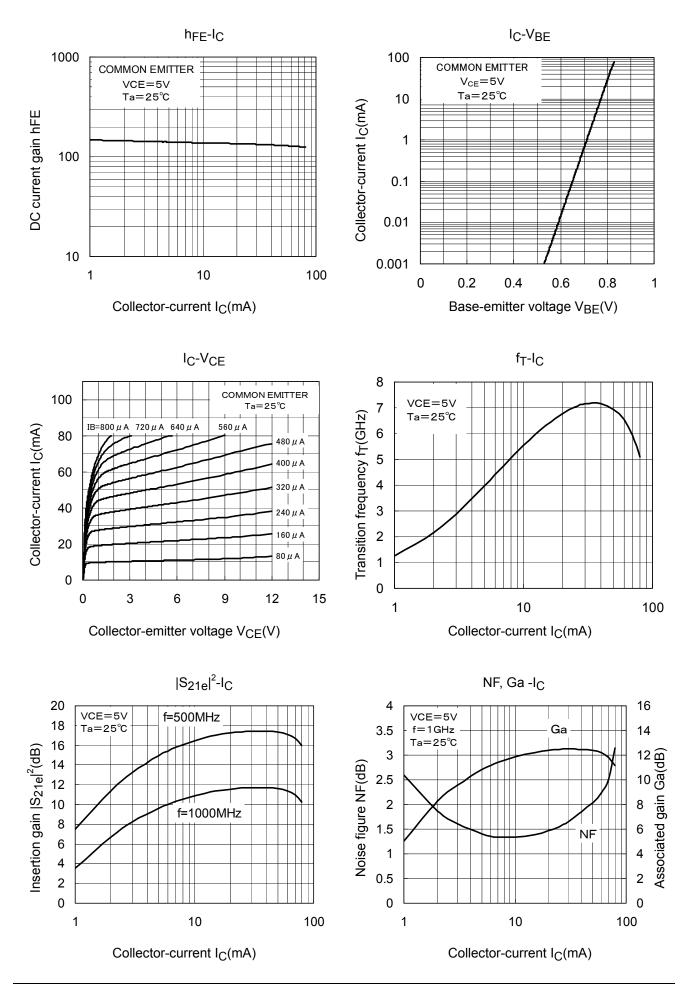
Note.3 : C_{re} is measured using a 3-terminal method with capacitance bridge

Caution:

This device is sensitive to electrostatic discharge.

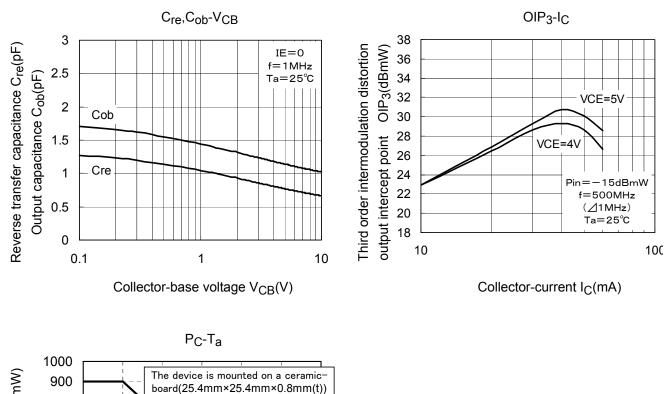
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MT3S20TU



Collector power dissipation P_C(mW)

Device only

Ambient temperature Ta(°C)

2009-12-09

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